BPV11

Vishay Semiconductors

Silicon NPN Phototransistor

FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- · High photo sensitivity
- High radiant sensitivity
- · Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\phi = \pm 15^{\circ}$
- · Base terminal connected
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

· Detector for industrial electronic circuitry, measurement and control

PRODUCT SUMMARY COMPONENT Ica (mA) φ (deg) λ_{0.1} (nm) BPV11 450 to 1080 10 ± 15

Note

DESCRIPTION

• Test condition see table "Basic Characteristics"

ORDERING INFORMATION							
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM				
BPV11	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾				

Note

· MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Collector base voltage		V _{CBO}	80	V			
Collector emitter voltage		V _{CEO}	70	V			
Emitter base voltage		V _{EBO}	5	V			
Collector current		Ι _C	50	mA			
Collector peak current	$t_p/T=0.5,t_p\leq 10\ ms$	I _{CM}	100	mA			
Power dissipation	$T_{amb} \le 47 \ ^{\circ}C$	Pv	150	mW			
Junction temperature		Тj	100	°C			
Operating temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 100	°C			
Soldering temperature	$t \le 5$ s, 2 mm from body	T _{sd}	260	°C			
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	350	K/W			

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RoHS

COMPLIANT

HALOGEN FREE

<u>GREEN</u>

(5-2008)



BPV11 is a silicon NPN phototransistor with high radiant

sensitivity in clear, T-1¾ plastic package with base terminal.

It is sensitive to visible and near infrared radiation.



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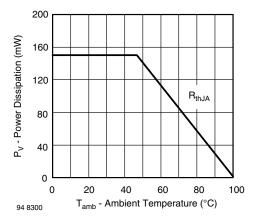


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Collector emitter breakdown voltage	I _C = 1 mA	V _{(BR)CEO}	70			V		
Collector emitter dark current	V _{CE} = 10 V, E = 0	I _{CEO}		1	50	nA		
DC current gain	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 5 \text{ mA}, \text{ E} = 0$	h _{FE}		450				
Collector emitter capacitance	$V_{CE} = 0 V, f = 1 MHz, E = 0$	C _{CEO}		15		pF		
Collector base capacitance	$V_{BE} = 0 V, f = 1 MHz, E = 0$	C _{CBO}		19		pF		
Collector light current	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $V_{CE} = 5 \text{ V}$	I _{ca}	3	10		mA		
Angle of half sensitivity		φ		± 15		deg		
Wavelength of peak sensitivity		λρ		850		nm		
Range of spectral bandwidth		λ _{0.1}		450 to 1080		nm		
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $I_C = 1 \text{ mA}$	V _{CEsat}		130	300	mV		
Turn-on time	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	t _{on}		6		μs		
Turn-off time	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	t _{off}		5		μs		
Cut-off frequency	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	f _c		110		kHz		

BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

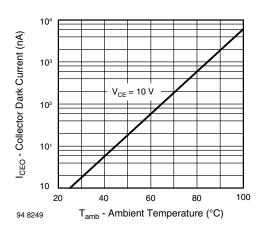


Fig. 2 - Collector Dark Current vs. Ambient Temperature

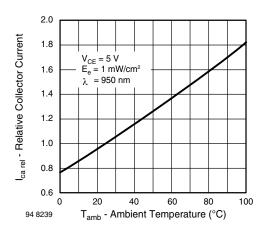


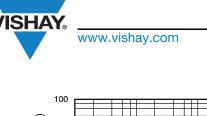
Fig. 3 - Relative Collector Current vs. Ambient Temperature

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2 For technical questions, contact: <u>detectortechsupport@vishay.com</u>

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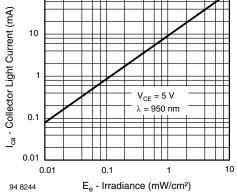


Fig. 4 - Collector Light Current vs. Irradiance

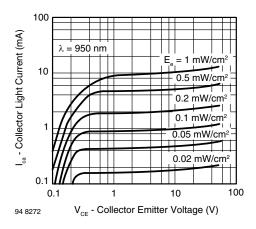


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

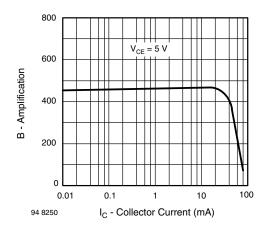


Fig. 6 - Amplification vs. Collector Current

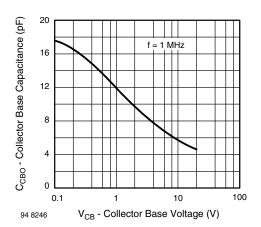


Fig. 7 - Collector Base Capacitance vs. Collector Base Voltage

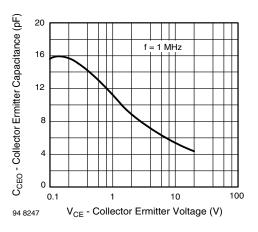


Fig. 8 - Collector Emitter Capacitance vs. Collector Emitter Voltage

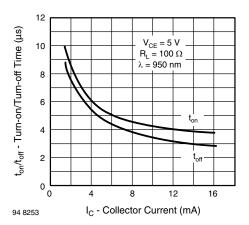
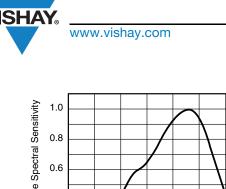


Fig. 9 - Turn-on/Turn-off Time vs. Collector Current

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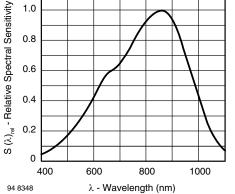
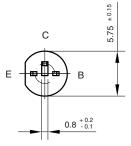


Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

PACKAGE DIMENSIONS in millimeters



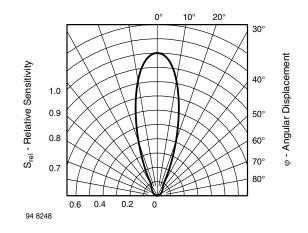
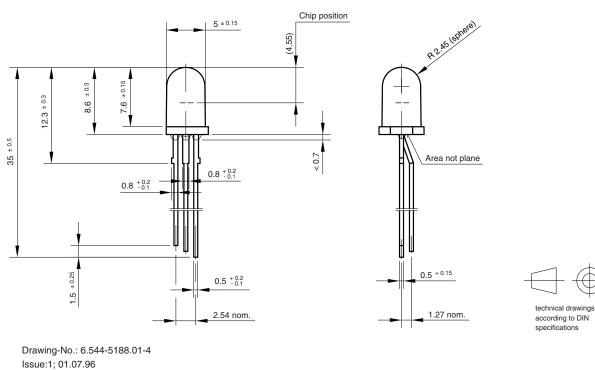


Fig. 11 - Relative Radiant Sensitivity vs. Angular Displacement



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